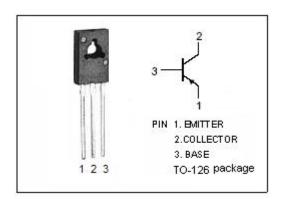


isc Silicon PNP Power Transistor

2SA1214

DESCRIPTION

- Collector-Emitter Breakdown Voltage-V_{(BR)CEO}= -50V (Min)
- · Good Linearity of hFE
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

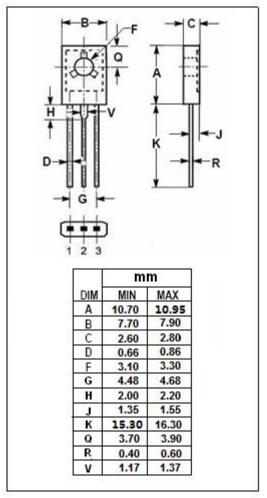


APPLICATIONS

• Desinged for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-60	V	
Vceo	Collector-Emitter Voltage	-50	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-2	А	
P _C	Collector Power Dissipation @ T _a =25℃	1.5	- W	
	Total Power Dissipation @ T _C =25℃	25		
TJ	Junction Temperature 150		$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	°C	





isc Silicon PNP Power Transistor

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ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -1mA; I _B = 0	-50			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -0.1mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -1A; I _B = -0.1A			-1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = -1A; I _B = -0.1A			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -60V; I _E = 0			-1.0	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-1.0	μА
h _{FE}	DC Current Gain	I _C = -150mA; V _{CE} = -2V	60		320	
f⊤	Current-Gain—Bandwidth Product	I _C = -100mA; V _{CE} = -10V		35		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1.0MHz		45		pF

NOTICE:

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